

isc N-Channel MOSFET Transistor

IRFSL4227

FEATURES

- Static drain-source on-resistance:
 R_{DS}(on)≤22mΩ
- Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

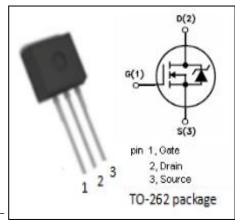
· Fast switching

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	200	V	
V _{GS}	Gate-Source Voltage	±30	V	
I _D	Drain Current-Continuous	62	А	
I _{DM}	Drain Current-Single Pulsed	260	А	
P _D	Total Dissipation @T _c =25℃	330	W	
Тј	Max. Operating Junction Temperature	175	°C	
T _{stg}	Storage Temperature	-40~175	°C	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(j-c)	Channel-to-case thermal resistance	0.45	°C/W



	N 10			28
b2 .		A		
		n	ım	
	DIM	MIN	MAX	
	A	4.37	4.77	
	A1	1.22	1.42	
	A2	2.47	2.87	
	Ъ	0.70	0.97	
	Ъ2	1.17	1.42	
	С	0.28	0.53	1
	D	23.20	24.02]
	D1	8.38	8.90	
	D2	6.00	=8]
	E	9.90	10.39	1
	E4	7.30	_]
	е	2.54BSC		
	G	1.25	1.50]
	H2	3	1.31	1
	L	13.34	14.10]
				1
	L1	3.30	4.06	1



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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =250 μ A	200			V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	VDS=VGS; I _D =250 μ A	3		5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D =46A			22	$\mathbf{m}\Omega$
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V			±0.1	μ A
I _{DSS}	Drain-Source Leakage Current	V _{DS} =200V; V _{GS} = 0V			20	μ А
V _{SD}	Diode forward voltage	I _s =46A, V _{GS} = 0V			1.3	V



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